

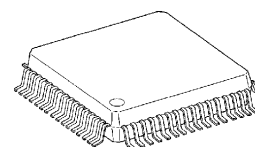
## CMOS 8-Bit Microcontroller

## TMP86PM72FG

The TMP86PM72 is a OTP type MCU which includes 32-Kbyte one-time PROM. It is a pin compatible with a mask ROM product of the TMP86CH72/CM72. Writing the program to built-in PROM, the TMP86PM72 operates as the same way as the TMP86CH72/CM72. Using the Adapter socket, you can write and verify the data for the TMP86PM72 with a general-purpose PROM programmer same as TC571000D/AD.

Product No.	OTP	RAM	Package	Adapter Socket
TMP86PM72FG	32 K × 8 bits	1 K × 8 bits	P-QFP64-1414-0.80C	BM11707

P-QFP64-1414-0.80C



TMP86PM72FG

030619EBP1

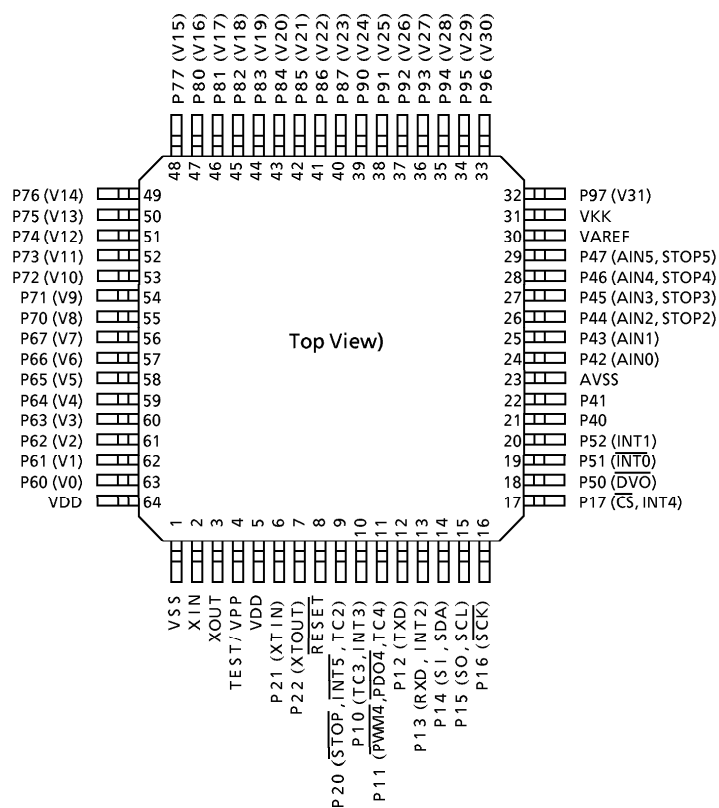
- The information contained herein is subject to change without notice.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA for any infringements of patents or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of TOSHIBA or others.
- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- The products described in this document are subject to the foreign exchange and foreign trade laws.
- TOSHIBA products should not be embedded to the downstream products which are prohibited to be produced and sold, under any law and regulations.
- For a discussion of how the reliability of microcontrollers can be predicted, please refer to Section 1.3 of the chapter entitled Quality and Reliability Assurance / Handling Precautions.



Purchase of TOSHIBA I<sup>2</sup>C components conveys a license under the Philips I<sup>2</sup>C Patent Rights to use these components in an I<sup>2</sup>C system, provided that the system conforms to the I<sup>2</sup>C Standard Specification as defined by Philips.

## Pin Assignments (Top View)

P-QFP64-1414-0.80C



Note: All VDD terminals are connected externally.

## Pin Function

The TMP86PM72 has MCU mode and PROM mode.

### (1) MCU mode

In the MCU mode, the TMP86PM72 is a pin compatible with the TMP86CH72/CM72 (Make sure to fix the TEST pin to low level).

### (2) PROM mode

Pin name (PROM mode)	Input/Output	Functions	Pin Name (MCU mode)
A16 to A12	Input	Input of Memory address for program	PD4 to PD0
A11 to A8			P53 to P50
A7 to A0			P47 to P40
D7 to D0	I/O	Input/Output of Memory data for program	P17 to P10
$\overline{CE}$	Input	Chip enable	P95
$\overline{OE}$		Output enable	P94
$\overline{PGM}$		Program control	P93
VPP	Power supply	+ 12.75 V/5 V (Power supply of program)	TEST
VDD		+ 6.25 V/5 V	VDD
GND		0 V	VSS
P51, P21	I/O	PROM mode setting pin. Fix to high.	
P50, P20, P22, AVSS, VAREF		PROM mode setting pin. Fix to low.	
RESET			
XIN	Input	Self oscillation with resonator (10 MHz)	
XOUT	Output		

## Operation

This section describes the functions and basic operational blocks of TMP86PM72.

The TMP86PM72 has PROM in place of the mask ROM which is included in the TMP86CH72/CM72.

In addition, TMP86PM72 operates as the single clock mode when releasing reset.

When using the dual clock mode, oscillate a low-frequency clock by [SET (SYSCR2). XTEN] command at the beginning of program.

### 1. Operating Mode

The TMP86PM72 has MCU mode and PROM mode.

#### 1.1 MCU Mode

The MCU mode is set by fixing the TEST/VPP pin to the low level. (TEST/VPP pin cannot be used open because it has no built-in pull-down resistor).

##### 1.1.1 Program Memory

The TMP86PM72 has a 32 Kbyte built-in one time PROM (addresses 8000<sub>H</sub> to FFFF<sub>H</sub> in the MCU mode, addresses 0000<sub>H</sub> to 7FFF<sub>H</sub> in the PROM mode).

When using TMP86PM72 for evaluation of mask ROM products, the program is written in the program storing area shown in Figure 1-1.

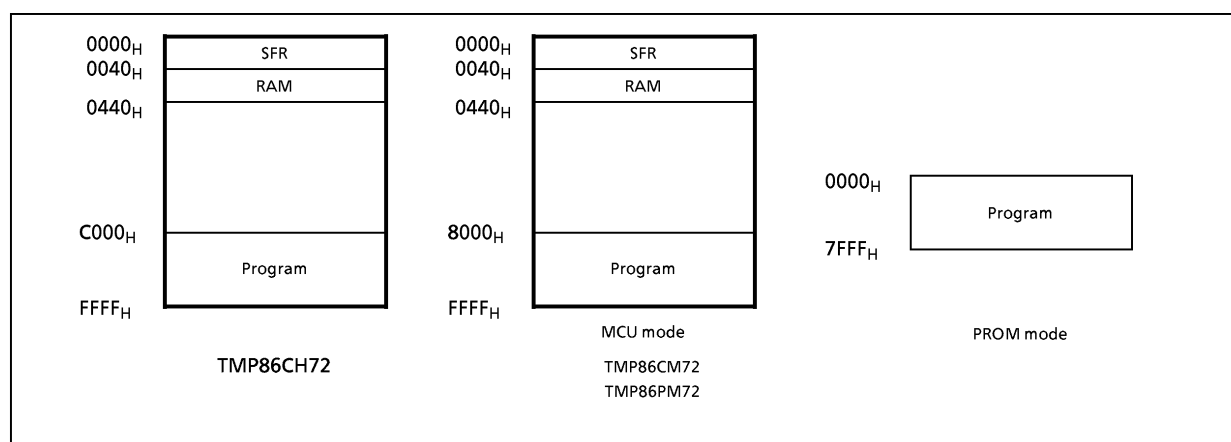


Figure 1-1. Program Memory Area

**Note:** The area that is not in use should be set data to FFH, or a general-purpose PROM programmer should be set only in the program memory area to access.

## Electrical Characteristics

## Absolute Maximum Ratings

(V<sub>SS</sub> = 0 V)

Parameter		Symbol	Pins	Rating	Unit
Supply voltage		V <sub>DD</sub>		– 0.3 to 6.5	V
Program voltage		V <sub>PP</sub>	TEST/V <sub>PP</sub>	– 0.3 to 13.0	
Input voltage		V <sub>IN</sub>		– 0.3 to V <sub>DD</sub> + 0.3	
Output voltage		V <sub>OUT1</sub>		– 0.3 to V <sub>DD</sub> + 0.3	
		V <sub>OUT2</sub>	Source open drain ports	V <sub>DD</sub> – 41 to V <sub>DD</sub> + 0.3	
Output current (per 1 pin)	IOL	I <sub>OUT1</sub>	P0, P1, P2, P4 (P42~P47), P5 ports	5	mA
		I <sub>OUT2</sub>	P4 (P40, P41) port	40	
	IOH	I <sub>OUT3</sub>	P0, P1, P4, P5 ports	– 3	
		I <sub>OUT4</sub>	P6, P7 ports	– 30	
		I <sub>OUT5</sub>	P8, P9 ports	– 20	
	Output current (total)		ΣI <sub>OUT1</sub>	P0, P1, P2, P4, P5 ports	120
			ΣI <sub>OUT2</sub>	P6, P7, P8, P9 ports	– 120
Power dissipation [T <sub>opr</sub> = 25°C]		PD		1200	mW
Soldering temperature (time)		T <sub>sld</sub>		260 (10 μ)	°C
Storage temperature		T <sub>stg</sub>		– 55 to 125	
Operating temperature		T <sub>opr</sub>		– 30 to 70	

**Note:** The absolute maximum ratings are rated values which must not be exceeded during operation, even for an instant. Any one of the ratings must not be exceeded. If any absolute maximum rating is exceeded, a device may break down or its performance may be degraded, causing it to catch fire or explode resulting in injury to the user. Thus, when designing products which include this device, ensure that no absolute maximum rating value will ever be exceeded.

Recommended Operating Condition	(V <sub>SS</sub> = 0 V, Topr = – 30 to 70°C)
---------------------------------	--

Parameter	Symbol	Pins	Condition		Min	Max	Unit
Supply voltage	V <sub>DD</sub>		fc = 16 MHz	NORMAL1/2 modes	4.5	5.5	V
				IDLE0, 1/2 modes			
			fc = 8 MHz	NORMAL1/2 modes	2.7		
				IDLE0, 1/2 modes			
			fs = 32.768 kHz	SLOW mode			
				SLEEP mode			
	STOP mode						
Output voltage	V <sub>OUT3</sub>	Source open drain ports			V <sub>DD</sub> – 38	V <sub>DD</sub>	
Input high level	V <sub>IH1</sub>	Except hysteresis input	V <sub>DD</sub> ≤ 4.5 V		V <sub>DD</sub> × 0.70	V <sub>DD</sub>	
	V <sub>IH2</sub>	Hysteresis input			V <sub>DD</sub> × 0.75		
	V <sub>IH3</sub>	TTL input			V <sub>DD</sub> × 0.90		
Input low level	V <sub>IL1</sub>	Except hysteresis input	V <sub>DD</sub> ≤ 4.5 V		0	V <sub>DD</sub> × 0.30	
	V <sub>IL2</sub>	Hysteresis input				V <sub>DD</sub> × 0.25	
	V <sub>IL3</sub>	TTL input			V <sub>DD</sub> × 0.10	V <sub>DD</sub>	
Clock frequency	fc	XIN, XOUT	V <sub>DD</sub> = 2.7 to 5.5 V		1.0	8.0	MHz
			V <sub>DD</sub> = 4.5 to 5.5 V			16.0	
	fs	XTIN, XTOUT			30.0	34.0	kHz

**Note:** The recommended operating conditions for a device are operating conditions under which it can be guaranteed that the device will operate as specified. If the device is used under operating conditions other than the recommended operating conditions (Supply voltage, operating temperature range, specified AC/DC values etc.), malfunction may occur. Thus, when designing products which include this device, ensure that the recommended operating conditions for the device are always adhered to.

## DC Characteristics (1)

(V<sub>DD</sub> = 5 V)

[Condition] V<sub>DD</sub> = 5.0 V ± 10%, V<sub>SS</sub> = A<sub>VSS</sub> = 0 V, T<sub>opr</sub> = -30~70°C  
(Typ.: V<sub>DD</sub> = 5.0 V, T<sub>opr</sub> = 25°C, V<sub>in</sub> = 5.0 V/0 V)

Parameter	Symbol	Pins	Condition	Min	Typ.	Max	Unit		
Hysteresis voltage	V <sub>HS</sub>	Hysteresis input		–	0.9	–	V		
Input current	I <sub>IN1</sub>	TEST	V <sub>DD</sub> = 5.5 V, V <sub>IN</sub> = 5.5 V/0 V	–	–	± 2	μA		
	I <sub>IN2</sub>	Sink open drain, Tri-st							
	I <sub>IN3</sub>	RESET, STOP							
Input resistance	R <sub>IN</sub>	RESET pull-up		100	220	450	kΩ		
Pull-down resistance (Note 4)	R <sub>K</sub>	Source open drain, Tri-st	V <sub>DD</sub> = 5.5 V, V <sub>KK</sub> = – 30 V	50	80	120			
Output leakage current	I <sub>LO1</sub>	Sink open drain, Tri-st	V <sub>DD</sub> = 5.5 V, V <sub>OUT</sub> = 5.5 V/0 V	–	–	± 2	μA		
	I <sub>LO2</sub>	Source open drain	V <sub>DD</sub> = 5.5 V, V <sub>KK</sub> = – 32 V	–	–	± 2			
Output high voltage	V <sub>OH</sub>	Tri-st port	V <sub>DD</sub> = 4.5 V, I <sub>OH</sub> = – 0.7 mA	4.1	–	–	V		
Output low voltage	V <sub>OL1</sub>	Except XOUT and (P40, P41) Port	V <sub>DD</sub> = 4.5 V, I <sub>OL</sub> = 1.6 mA	–	–	0.4			
Output high current	I <sub>OH1</sub>	P6, P7	V <sub>DD</sub> = 4.5 V, V <sub>OH</sub> = 2.4 V	– 18	– 28	–	mA		
	I <sub>OH2</sub>	P8, P9, PD	V <sub>DD</sub> = 4.5 V, V <sub>OH</sub> = 2.4 V	– 9	– 14	–			
Output low current	I <sub>OL</sub>	High current port (P40, P41)	V <sub>DD</sub> = 4.5 V, V <sub>OL</sub> = 1.0 V	–	20	–			
Supply current in NORMAL1/2 modes	I <sub>DD</sub>		fc = 16.0 MHz fs = 32.768 kHz	AD converter disable (IREF off)	–	12	18	mA	
			fc = 8.0 MHz fs = 32.768 kHz		–	6	9		
Supply current in IDLE0/1/2 modes			fc = 16.0 MHz fs = 32.768 kHz		–	6	9		
			fc = 8.0 MHz fs = 32.768 kHz		–	3	4.5		
Supply current in NORMAL1/2 modes			fc = 16.0 MHz fs = 32.768 kHz	AD converter enable	–	13	19		
			fc = 8.0 MHz fs = 32.768 kHz		–	7	10		
Supply current in STOP mode			Topr = to 50℃	AD converter disable	–	0.5	5	μA	
			Topr = to 70℃		–		10		

Note 1: Typical values show those at T<sub>opr</sub> = 25°C, V<sub>DD</sub> = 5 V.

Note 2: Input current (I<sub>IN1</sub>, I<sub>IN3</sub>): The current through pull-up or pull-down resistor is not included.

Note 3: I<sub>DD</sub> does not include I<sub>REF</sub> current.

Note 4: T<sub>opr</sub> = -10°C to 70°C

## DC Characteristics (2)

(V<sub>DD</sub> = 3 V)

[Condition] V<sub>DD</sub> = 3.0 V ± 10%, V<sub>SS</sub> = A<sub>VSS</sub> = 0 V, T<sub>opr</sub> = –30 to 70°C  
(Typ.: V<sub>DD</sub> = 3.0 V, T<sub>opr</sub> = 25°C, V<sub>in</sub> = 3.0 V/0 V)

Parameter	Symbol	Pins	Condition	Min	Typ.	Max	Unit	
Hysteresis voltage	V <sub>HS</sub>	Hysteresis input		–	0.4	–	V	
Input current	I <sub>IN1</sub>	TEST	V <sub>DD</sub> = 3.3 V, V <sub>IN</sub> = 3.3 V/0 V	–	–	± 2	μA	
	I <sub>IN2</sub>	Sink open drain, Tri-st						
	I <sub>IN3</sub>	RESET, STOP						
Input resistance	R <sub>IN</sub>	RESET pull-up		100	220	450	kΩ	
Pull-down resistance	R <sub>K</sub>	Source open drain, tri-st	V <sub>DD</sub> = 3.3 V, V <sub>KK</sub> = – 30 V	45	75	115		
Output leakage current	I <sub>LO1</sub>	Sink open drain, tri-st	V <sub>DD</sub> = 3.3 V, V <sub>OUT</sub> = 3.3 V/0 V	–	–	± 2	μA	
	I <sub>LO2</sub>	Source open drain	V <sub>DD</sub> = 3.3 V, V <sub>KK</sub> = – 32 V	–	–	± 2		
Output high voltage	V <sub>OH</sub>	Tri-st port	V <sub>DD</sub> = 2.7 V, I <sub>OH</sub> = – 0.6 mA	2.3	–	–	V	
Output low voltage	V <sub>OL1</sub>	Except XOUT and (P40, P41) Port	V <sub>DD</sub> = 2.7 V, I <sub>OL</sub> = 0.9 mA	–	–	0.4		
Output high current	I <sub>OH1</sub>	P6, P7	V <sub>DD</sub> = 2.7 V, V <sub>OH</sub> = 1.5 V	– 5.5	– 8	–	mA	
	I <sub>OH2</sub>	P8, P9, PD	V <sub>DD</sub> = 2.7 V, V <sub>OH</sub> = 1.5 V	– 3	– 4.5	–		
Output low current	I <sub>OL</sub>	High current port (P40, P41) port	V <sub>DD</sub> = 2.7 V, V <sub>OL</sub> = 1.0 V	–	6	–		μA
Supply current in NORMAL1/2 modes	I <sub>DD</sub>		fc = 8.0 MHz fs = 32.768 kHz	AD converter disable (IREF off)	–	3	4.5	
Supply current in IDLE0/1/2 modes			fc = 8.0 MHz fs = 32.768 kHz		–	2	2.5	
Supply current in NORMAL1/2 modes			fc = 8.0 MHz fs = 32.768 kHz	AD converter enable	–	3.5	5	
Supply current in SLOW1 mode			fs = 32.768 kHz	AD converter disable	–	30	60	
Supply current in SLEEP0, 1 mode					–	15	30	
Supply current in STOP mode					Topr = to 50°C	–	0.5	
			Topr = to 70°C		10			

Note 1: Typical values show those at T<sub>opr</sub> = 25°C, V<sub>DD</sub> = 3 V.

Note 2: Input current (I<sub>IN1</sub>, I<sub>IN3</sub>): The current through pull-up or pull-down resistor is not included.

Note 3: I<sub>DD</sub> does not include I<sub>REF</sub> current.

Note 4: The supply currents of SLOW2 and SLEEP2 modes are equivalent IDLE0, 1, 2.

## AD Conversion Characteristics

(V<sub>SS</sub> = 0.0 V, 4.5 V ≤ V<sub>DD</sub> ≤ 5.5 V, Topr = –30 to 70°C)

Parameter	Symbol	Condition	Min	Typ.	Max	Unit
Analog reference voltage	V <sub>AREF</sub>		V <sub>DD</sub> – 1.5	–	V <sub>DD</sub>	V
Analog reference GND	A <sub>VSS</sub>		V <sub>SS</sub>			
Analog reference voltage range (Note 4)	△V <sub>AREF</sub>		3.0	–	–	
Analog input voltage	V <sub>AIN</sub>		V <sub>SS</sub>	–	V <sub>AREF</sub>	
Power supply current of analog reference voltage	I <sub>REF</sub>	V <sub>DD</sub> = V <sub>AREF</sub> = 5.5 V V <sub>SS</sub> = A <sub>VSS</sub> = 0.0 V	–	0.6	1.0	mA
Non linearity error		V <sub>DD</sub> = V <sub>AREF</sub> = 4.5 to 5.0 V, V <sub>SS</sub> = A <sub>VSS</sub> = 0.0 V	–	–	± 1	LSB
Zero point error			–	–	± 1	
Full scale error			–	–	± 1	
Total error			–	–	± 2	

(V<sub>SS</sub> = 0.0 V, 2.7 V ≤ V<sub>DD</sub> < 4.5 V, Topr = –30 to 70°C)

Parameter	Symbol	Condition	Min	Typ.	Max	Unit
Analog reference voltage	V <sub>AREF</sub>		V <sub>DD</sub> – 1.5	–	V <sub>DD</sub>	V
Analog reference GND	A <sub>VSS</sub>		V <sub>SS</sub>			
Analog reference voltage range (Note 4)	ΔV <sub>AREF</sub>		2.5	–	–	
Analog input voltage	V <sub>AIN</sub>		V <sub>SS</sub>	–	V <sub>AREF</sub>	
Power supply current of analog reference voltage	I <sub>REF</sub>	V <sub>DD</sub> = V <sub>AREF</sub> = 4.5 V V <sub>SS</sub> = A <sub>VSS</sub> = 0.0 V	–	0.5	0.8	mA
Non linearity error		V <sub>DD</sub> = A <sub>VDD</sub> = 2.7 V to 4.5 V V <sub>SS</sub> = A <sub>VSS</sub> = 0.0 V	–	–	± 1	LSB
Zero point error			–	–	± 1	
Full scale error			–	–	± 1	
Total error			–	–	± 2	

Note 1: The total error includes all errors except a quantization error, and is defined as a maximum deviation from the ideal conversion line.

Note 2: Conversion time is different in recommended value by power supply voltage.

About conversion time, please refer to "2.11.2 Register Configuration".

Note 3: Please use input voltage to AIN input Pin in limit of V<sub>AREF</sub> – V<sub>SS</sub>.

When voltage of range outside is input, conversion value becomes unsettled and gives affect to other channel conversion value.

Note 4: Analog Reference Voltage Range: ΔV<sub>AREF</sub> = V<sub>AREF</sub> – V<sub>SS</sub>

## AC Characteristics

(V<sub>SS</sub> = 0 V, V<sub>DD</sub> = 4.5 to 5.5 V, T<sub>opr</sub> = – 30 to 70°C)

Parameter	Symbol	Condition	Min	Typ.	Max	Unit
Machine cycle time	tcy	NORMAL1/2 modes	0.25	–	4	$\mu$ s
		IDLE1/2 modes				
		SLOW1/2 modes	117.6	–	133.3	
		SLEEP1/2 modes				
High level clock pulse width	twcH	For external clock operation (XIN input) fc = 16 MHz	–	31.25	–	ns
Low level clock pulse width	twcL					
High level clock pulse width	twcH	For external clock operation (XTIN input) fc = 32.768 kHz	–	15.26	–	$\mu$ s
Low level clock pulse width	twcL					

(V<sub>SS</sub> = 0 V, V<sub>DD</sub> = 2.7 to 4.5 V, T<sub>opr</sub> = – 30 to 70°C)

Parameter	Symbol	Condition	Min	Typ.	Max	Unit
Machine cycle time	tcy	NORMAL1/2 modes	0.5	–	8	$\mu$ s
		IDLE1/2 modes				
		SLOW1/2 modes	117.6	–	133.3	
		SLEEP1/2 modes				
High level clock pulse width	twcH	For external clock operation (XIN input) fc = 8 MHz	–	62.5	–	ns
Low level clock pulse width	twcL					
High level clock pulse width	twcH	For external clock operation (XTIN input) fc = 32.768 kHz	–	15.26	–	$\mu$ s
Low level clock pulse width	twcL					

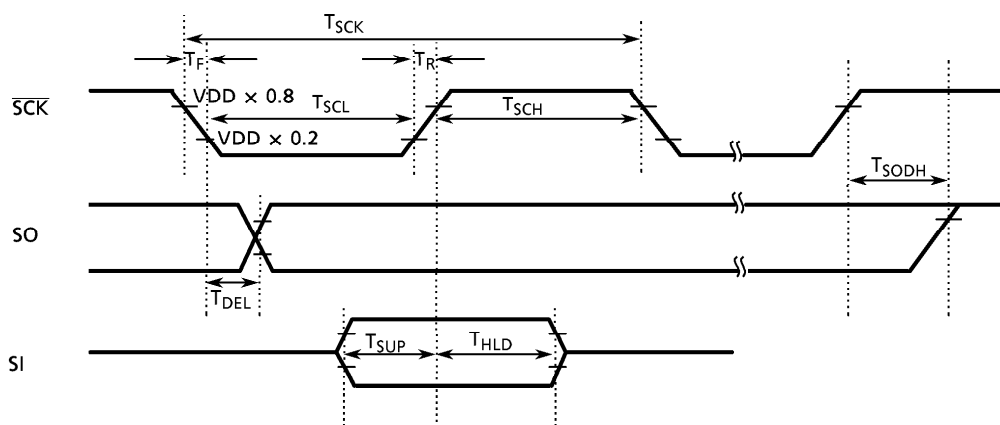
## HSIO AC Characteristics

(V<sub>SS</sub> = 0 V, 2.7 V ≤ V<sub>DD</sub> ≤ 5.5 V, T<sub>opr</sub> = –30 to 70°C)

Parameter	Symbol	Conditions	Min	Typ.	Max	Unit
SCK output period (Internal clock)	T <sub>SCK1</sub>	8 MHz < f <sub>c</sub> ≤ 16 MHz V <sub>DD</sub> = 4.5 V to 5.5 V	16/f <sub>c</sub>	–	–	s
SCK output low width (Internal clock)	T <sub>SCL1</sub>		8/f <sub>c</sub> – 100ns	–	–	
SCK output high width (Internal clock)	T <sub>SCH1</sub>		8/f <sub>c</sub> – 100ns	–	–	
SCK output period (Internal clock)	T <sub>SCK2</sub>	4 MHz < f <sub>c</sub> ≤ 8 MHz V <sub>DD</sub> = 2.7 V to 5.5 V	8/f <sub>c</sub>	–	–	
SCK output low width (Internal clock)	T <sub>SCL2</sub>		4/f <sub>c</sub> – 100ns	–	–	
SCK output high width (Internal clock)	T <sub>SCH2</sub>		4/f <sub>c</sub> – 100ns	–	–	
SCK output period (Internal clock)	T <sub>SCK3</sub>	f <sub>c</sub> ≤ 4 MHz V <sub>DD</sub> = 2.7 V to 5.5 V	4/f <sub>c</sub>	–	–	
SCK output low width (Internal clock)	T <sub>SCL3</sub>		2/f <sub>c</sub> – 100ns	–	–	
SCK output high width (Internal clock)	T <sub>SCH3</sub>		2/f <sub>c</sub> – 100ns	–	–	
SCK input period (External clock)	T <sub>SCK4</sub>	f <sub>c</sub> ≤ 8 MHz (V <sub>DD</sub> = 2.7 V to 5.5 V)	800	–	–	ns
SCK input low width (External clock)	T <sub>SCL4</sub>		300 (Note 1)	–	–	
SCK input low width (External clock)	T <sub>SCH4</sub>		300 (Note 1)	–	–	
SI input setup time	T <sub>SUP</sub>	V <sub>DD</sub> = 3.0 V, CL = 50pF (Note 2)	150	–	–	ns
SI input hold time	T <sub>HLD</sub>		150	–	–	
SO output delay time	T <sub>DEL</sub>		–	–	200	
Rising time	T <sub>R</sub>		–	–	100	
Falling time	T <sub>F</sub>		–	–	100	
SO last bit hold time	T <sub>SODH</sub>		16.5/f <sub>c</sub>	–	32.5/f <sub>c</sub>	

Note 1: T<sub>SCKL</sub>, T<sub>SCKH</sub> ≥ 2.5/f<sub>c</sub> (High-frequency clock mode), T<sub>SCKL</sub>, T<sub>SCKH</sub> ≥ 2.5/f<sub>c</sub> (Low-frequency clock mode)

Note 2: CL, external capacitance

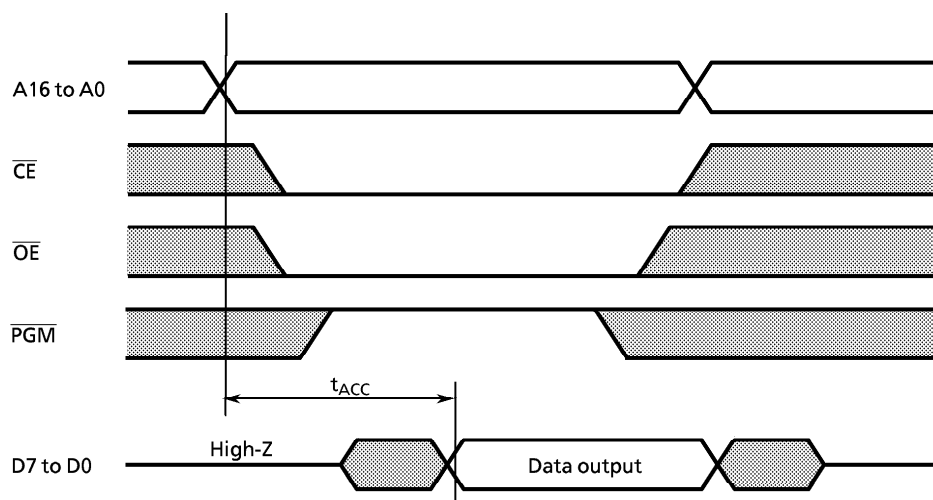


DC Characteristics, AC Characteristics (PROM mode) ( $V_{SS} = 0\text{ V}$ ,  $T_{opr} = 25 \pm 5^\circ\text{C}$ )

(1) Read operation in PROM mode

Parameter	Symbol	Conditions	Min	Typ.	Max	Unit
High level input voltage (TTL)	V <sub>IH3</sub>		2.2	–	V <sub>DD</sub>	V
Low leve input voltage (TTL)	V <sub>IL3</sub>		0	–	0.8	
Power supply	V <sub>DD</sub>		4.75	5.0	5.25	
Power supply of program	V <sub>PP</sub>					
Address access time	t <sub>ACC</sub>	V <sub>DD</sub> = 5.0 ± 0.25 V	–	1.5t <sub>cyc</sub> + 300	–	ns

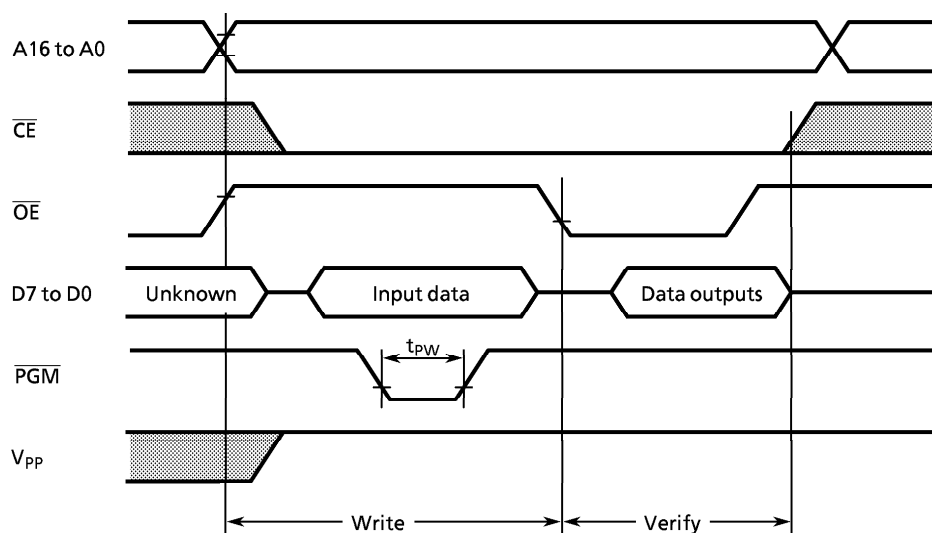
Note:  $t_{cyc} = 400\text{ ns}$  at 10 MHz



(2) Program operation (High-speed) ( $T_{opr} = 25 \pm 5^\circ\text{C}$ )

Parameter	Symbol	Conditions	Min	Typ.	Max	Unit
High level input voltage (TTL)	$V_{IH3}$		2.2	–	$V_{DD}$	V
Low level input voltage (TTL)	$V_{IL3}$		0	–	0.8	
Power supply	$V_{DD}$		6.0	6.25	6.5	
Power supply of program	$V_{PP}$		12.5	12.75	13.0	
Pulse width of initializing program	$t_{PW}$	$V_{DD} = 6.0\text{ V}$	0.095	0.1	0.105	ms

## High-speed program writing



**Note 1:** The power supply of  $V_{PP}$  (12.75 V) must be set power-on at the same time or the later time for a power supply of  $V_{DD}$  and must be clear power-on at the same time or early time for a power supply of  $V_{DD}$ .

**Note 2:** The pulling up/down device on the condition of  $V_{PP} = 12.75\text{ V} \pm 0.25\text{ V}$  causes a damage for the device. Do not pull up/down at programming.

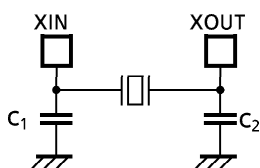
**Note 3:** Use the recommended adapter and mode.

Using other than the above condition may cause the trouble of the writting.

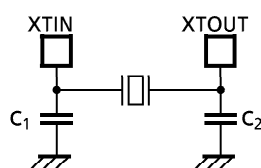
## Recommended Oscillating Conditions

(V<sub>SS</sub> = 0 V, T<sub>opr</sub> = – 30 to 70°C)

Parameter	Oscillator	Oscillation Frequency	VDD	Recommended Oscillator	Recommended Constant	
					C <sub>1</sub>	C <sub>2</sub>
High-frequency oscillation	Ceramic resonator	16 MHz	4.5 V to 5.5 V	MURATA CSA16.00MXZ040	10 pF	10 pF
		8 MHz	2.7 V to 5.5 V	MURATA CSA8.00MTZ CST8.00MTW	30 pF 30 pF (built-in)	30 pF 30 pF (built-in)
		4.19 MHz	2.7 V to 5.5 V	MURATA CSA4.19MG CST4.19MGW	30 pF 30 pF (built-in)	30 pF 30 pF (built-in)
Low-frequency oscillation	Crystal oscillator	32.768 kHz	2.7 V to 5.5 V	SII VT-200	6 pF	6 pF



(1) High-frequency Oscillation



(2) Low-frequency Oscillation

**Note 1:** An electrical shield by metal shield plate on the surface of IC package is recommended in order to protect the device from the high electric field stress applied from CRT (Cathodic Ray Tube) for continuous reliable operation.

**Note2:** When using the device (oscillator) in places exposed to high electric fields such as cathode-ray tubes, we recommend electrically shielding the package in order to maintain normal operating condition.

**Note 3:** The product numbers and specifications of the resonators by Murata Manufacturing Co., Ltd. are subject to change.

For up-to-date information, please refer to the following URL;

<http://www.murata.co.jp/search/index.html>